# MSKSEMI 美森科













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## **RB521S30T1G(MS)**

**Product specification** 





### **Features**

- UltraSmallmoldtype.(SOD-523)
- LowIR
- Highreliability.

## **Applications**

Lowcurrentrectification

#### Construction

Siliconepitaxialplanar

## **MechanicalCharacteristics**

- Leadfinish:100%matteSn(Tin)
- Mountingposition:Any
- Qualifiedmaxreflowtemperature:260 °C
- DevicemeetsMSL1requirements
- Puretinplating:7~17um
- Pinflatness:≤3mil

#### **Reference News**

| Outline | Pin Configuration | Marking |  |
|---------|-------------------|---------|--|
|         |                   | 5M *    |  |
| SOD-523 |                   |         |  |

## Electricalcharacteristicsperline@25℃

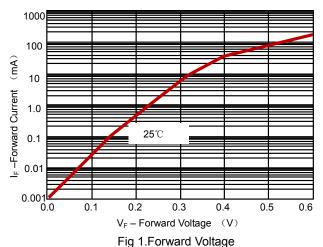
| Parameter       | Symbol     | Min. | Тур. | Max. | Unit | Conditions          |
|-----------------|------------|------|------|------|------|---------------------|
| Forward voltage | VF         | -    | -    | 0.5  | V    | l⊧=200mA            |
| Reverse current | <b>I</b> R | -    | -    | 30   | μΑ   | V <sub>R</sub> =10V |

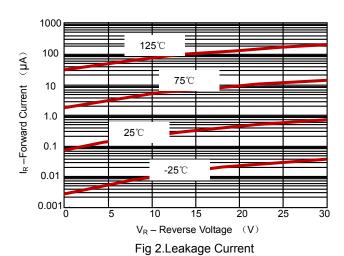
## Absolute maximum rating@25℃

| Parameter                              | Symbol          | limits      | Unit |
|--|-----------------|-------------|------|
| Reverse voltage (DC)                   | V <sub>RM</sub> | 30          | V    |
| Average rectified forward current      | Ь               | 200         | mA   |
| Forward current surge peak (60Hz 1cyc) | İfsm            | 1           | А    |
| Operating Junction temperature Range   | Tj              | -55 to 125  | °C   |
| Storage temperature                    | Tstg            | -40 to +125 | °C   |



## **Typical Characteristics**





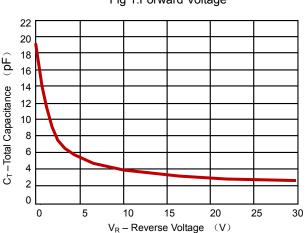
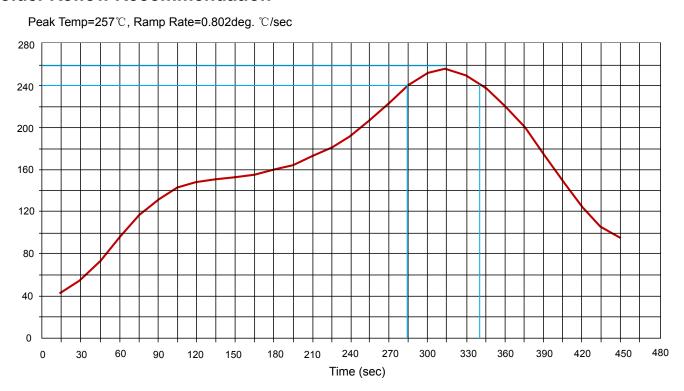


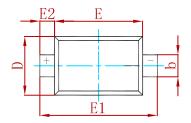
Fig 3.Total Capacitance

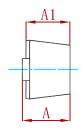
## **Solder Reflow Recommendation**

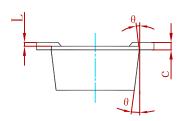




## PACKAGE MECHANICAL DATA

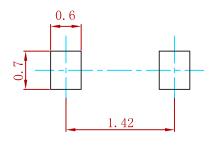






| Symbol   | Dimensions In Millimeters |       | Dimensions In Inches |       |  |
|----------|---------------------------|-------|----------------------|-------|--|
| Syllibol | Min                       | Max   | Min                  | Max   |  |
| Α        | 0.510                     | 0.770 | 0.020                | 0.031 |  |
| A1       | 0.500                     | 0.700 | 0.020                | 0.028 |  |
| b        | 0.250                     | 0.350 | 0.010                | 0.014 |  |
| С        | 0.080                     | 0.150 | 0.003                | 0.006 |  |
| D        | 0.750                     | 0.850 | 0.030                | 0.033 |  |
| E        | 1.100                     | 1.300 | 0.043                | 0.051 |  |
| E1       | 1.500                     | 1.700 | 0.059                | 0.067 |  |
| E2       | 0.200 REF                 |       | 300.0                | REF   |  |
| L        | 0.010                     | 0.070 | 0.001                | 0.003 |  |
| θ        | 7° F                      | REF   | 7° F                 | REF   |  |

## **Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

## **REELSPECIFICATION**

| P/N             | PKG     | QTY  |
|-----------------|---------|------|
| RB521S30T1G(MS) | SOD-523 | 3000 |



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